111. (Amended) An electroluminescence display device according to claim 109, wherein said first insulating layer has a planarized surface.

112. (Amended) An electroluminescence display device according to claim 109, wherein said electroluminescence display device is incorporated into an electric apparatus selected from the group consisting of a portable information terminal, a head mount display, a portable telephone, a video camera and a projector.

113. (Amended) An electroluminescence display device comprising:

at least one thin film transistor formed over a substrate;

a first insulating layer comprising silicon nitride formed over said thin film transistor;

a second insulating layer comprising organic resin formed over said first insulating layer;

a third insulating layer comprising DLC formed over said second insulating layer;

a pixel electrode formed over said third insulating layer, said pixel electrode electrically connected to said thin film transistor; and

a light-emitting layer formed over said third insulating layer.

114. (Amended) An electroluminescence display device according to claim 113, wherein said organic resin is selected from the group consisting of polyimide, polyimideamide, polyamide, acryl and epoxy.

115. (Amended) An electroluminescence display device according to claim 113, wherein said second insulating layer has a planarized surface.

116. (Amended) An electroluminescence display device according to claim 113, wherein said electroluminescence display device is incorporated into an electric

apparatus selected from the group consisting of a portable information terminal, a head mount display, a portable telephone, a video camera and a projector.

117. (Amended) An electroluminescence display device comprising:

at least one thin film transistor formed over a substrate;

a first insulating layer comprising organic resin formed over said thin film transistor;

a second insulating layer comprising DLC formed over said first insulating layer;

a third insulating layer comprising organic resin formed over said second insulating layer;

a pixel electrode formed over said third insulating layer, said pixel electrode electrically connected to said thin film transistor; and

a light-emitting layer formed over said third insulating layer.

118. (Amended) An electroluminescence display device according to claim 117, wherein said organic resin is selected from the group consisting of polyimide, polyimideamide, polyamide, acryl and epoxy.

119. (Amended) An electroluminescence display device according to claim 117, wherein said first insulating layer has a planarized surface.

120. (Amended) An electroluminescence display device according to claim 117, wherein said electroluminescence display device is incorporated into an electric apparatus selected from the group consisting of a portable information terminal, a head mount display, a portable telephone, a video camera and a projector.

121. (Amended) An electroluminescence display device comprising:

an active matrix region and a driver region formed over a substrate,

wherein said active matrix region comprises:

at least one thin film transistor;

a first insulating layer comprising organic resin formed over said thin film transistor;

a second insulating layer comprising DLC formed over said first insulating layer;

a pixel electrode formed over said second insulating layer, said pixel electrode electrically connected to said thin film transistor; and

a light-emitting layer formed over said second insulating layer.

122. (Amended) An electroluminescence display device according to claim 117, wherein said organic resin is selected from the group consisting of polyimide, polyimideamide, polyamide, acryl and epoxy.

123. (Amended) An electroluminescence display device according to claim 117, wherein said first insulating layer has a planarized surface.

124. (Amended) An electroluminescence display device according to claim 117, wherein said electroluminescence display device is incorporated into an electric apparatus selected from the group consisting of a portable information terminal, a head mount display, a portable telephone, a video camera and a projector.

125. (Amended) An electroluminescence display device comprising:

an active matrix region and a driver region over a substrate,

wherein said active matrix region comprises:

at least one thin film transistor;

a first insulating layer comprising silicon nitride formed over said thin film transistor;

a second insulating layer comprising organic resin formed over said first insulating layer;

a third insulating layer comprising DLC formed over said second insulting layer;

a pixel electrode formed over said third insulating layer, said pixel electrode electrically connected to said thin film transistor; and

a light-emitting layer formed over said third insulating layer.

126. (Amended) An electroluminescence display device according to claim 125, wherein said organic resin is selected from the group consisting of polyimide, polyimideamide, polyamide, acryl and epoxy.

127. (Amended) An electroluminescence display device according to claim 125, wherein said second insulating layer has a planarized surface.

128. (Amended) An electroluminescence display device according to claim 125, wherein said electroluminescence display device is incorporated into an electric apparatus selected from the group consisting of a portable information terminal, a head mount display, a portable telephone, a video camera and a projector.

129. (Amended) An electroluminescence display device comprising:

an active matrix region and a driver region over a substrate,

wherein said active matrix region comprises:

at least one thin film transistor;

a first insulating layer comprising organic resin formed over said thin film transistor;

a second insulating layer comprising DLC formed over said first insulating layer;

a third insulating layer comprising organic resin formed over said second insulating layer;

a pixel electrode formed over said third insulating layer, said pixel electrode electrically connected to said thin film transistor; and

a light-emitting layer formed over said third insulating layer.

130. (Amended) An electroluminescence display device according to claim 129, wherein said organic resin is selected from the group consisting of polyimide, polyimideamide, polyamide, acryl and epoxy.

131. (Amended) An electroluminescence display device according to claim 129, wherein said first insulating layer has a planarized surface.

132. (Amended) An electroluminescence display device according to claim 129, wherein said electroluminescence display device is incorporated into an electric apparatus selected from the group consisting of a portable information terminal, a head mount display, a portable telephone, a video camera and a projector.

133. (Amended) An electroluminescence display device comprising:

a switching element comprising at least one thin film transistor formed over a substrate;

a first insulating layer comprising organic resin formed over said switching element;

a second insulating layer comprising DLC formed over said first insulating layer;

a pixel electrode formed over said second insulating layer, said pixel electrode electrically connected to said thin film transistor; and

a light-emitting layer formed over said second insulating layer.

134. (Amended) An electroluminescence display device according to claim 133, wherein said organic resin is selected from the group consisting of polyimide, polyimideamide, polyamide, acryl and epoxy.

135. (Amended) An electroluminescence display device according to claim 133, wherein said first insulating layer has a planarized surface.

136. (Amended) An electroluminescence display device according to claim 133, wherein said electroluminescence display device is incorporated into an electric apparatus selected from the group consisting of a portable information terminal, a head mount display, a portable telephone, a video camera and a projector.

137. (Amended) An electroluminescence display device comprising:

a switching element comprising at least one thin film transistor formed over a substrate;

a first insulating layer comprising organic resin [for providing] having a flattened upper surface, formed over said switching element;

a second insulating layer comprising DLC formed over said first insulating layer;

a pixel electrode formed over said second insulating layer, said pixel electrode electrically connected to said thin film transistor; and

a light-emitting layer formed over said second insulating layer.

138. (Amended) An electroluminescence display device according to claim 137, wherein said organic resin is selected from the group consisting of polyimide, polyimideamide, polyamide, acryl and epoxy.

139. (Amended) An electroluminescence display device according to claim 137, wherein said first insulating layer has a planarized surface.

140. (Amended) An electroluminescence display device according to claim 137, wherein said electroluminescence display device is incorporated into an electric apparatus selected from the group consisting of a portable information terminal, a head mount display, a portable telephone, a video camera and a projector.